NSN 5961-01-083-8874

Diode Semiconductor Device - Page 1 of 1



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Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

5.9 breakdown voltage, dc

Current Rating Per Characteristic:

10.00 microamperes forward current, average peak

Power Rating Per Characteristic:

100.0 milliwatts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius case

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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